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# NOTICE OF ALLOWANCE AND FEE(S) DUE

7590

04/21/2004

HEWLETT-PACKARD COMPANY Intellectual Property Administration P.O. Box 272400 Fort Collins, CO 80527-2400 EXAMINER SANTIAGO, MARICELI

PAPER NUMBER

ART UNIT

DATE MAILED: 04/21/2004

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/845,845	04/30/2001	Xia Sheng	10007799-1	3212

TITLE OF INVENTION: SILICON EMITTER WITH LOW POROSITY HEAVILY DOPED CONTACT LAYER

APPLN. TYPE	SMALL ENTITY	ISSUE FEE	PUBLICATION FEE	TOTAL FEE(S) DUE	DATE DUE
nonprovisional	NO	\$1330	\$300	\$1630	07/21/2004

THE APPLICATION IDENTIFIED ABOVE HAS BEEN EXAMINED AND IS ALLOWED FOR ISSUANCE AS A PATENT. PROSECUTION ON THE MERITS IS CLOSED. THIS NOTICE OF ALLOWANCE IS NOT A GRANT OF PATENT RIGHTS. THIS APPLICATION IS SUBJECT TO WITHDRAWAL FROM ISSUE AT THE INITIATIVE OF THE OFFICE OR UPON PETITION BY THE APPLICANT. SEE 37 CFR 1.313 AND MPEP 1308.

THE ISSUE FEE AND PUBLICATION FEE (IF REQUIRED) MUST BE PAID WITHIN THREE MONTHS FROM THE MAILING DATE OF THIS NOTICE OR THIS APPLICATION SHALL BE REGARDED AS ABANDONED. THIS STATUTORY PERIOD CANNOT BE EXTENDED. SEE 35 U.S.C. 151. THE ISSUE FEE DUE INDICATED ABOVE REFLECTS A CREDIT FOR ANY PREVIOUSLY PAID ISSUE FEE APPLIED IN THIS APPLICATION. THE PTOL-85B (OR AN EQUIVALENT) MUST BE RETURNED WITHIN THIS PERIOD EVEN IF NO FEE IS DUE OR THE APPLICATION WILL BE REGARDED AS ABANDONED.

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- Applicant claims SMALL ENTITY status. See 37 CFR 1.27.
- II. PART B FEE(S) TRANSMITTAL should be completed and returned to the United States Patent and Trademark Office (USPTO) with your ISSUE FEE and PUBLICATION FEE (if required). Even if the fee(s) have already been paid, Part B Fee(s) Transmittal should be completed and returned. If you are charging the fee(s) to your deposit account, section "4b" of Part B Fee(s) Transmittal should be completed and an extra copy of the form should be submitted.
- III. All communications regarding this application must give the application number. Please direct all communications prior to issuance to Mail Stop ISSUE FEE unless advised to the contrary.

IMPORTANT REMINDER: Utility patents issuing on applications filed n r after Dec. 12, 1980 may require payment f maintenance fees. It is patentee's resp nsibility to ensure timely payment of maintenance fees when due.

#### PART B - FEE(S) TRANSMITTAL

C mplete and send this form, t gether with applicable fee(s), to: Mail

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INSTRUCTIONS: This form should be used for transmitting the ISSUE FEE and PUBLICATION FEE (if required). Blocks 1 through 4 should be completed where appropriate. All further correspondence including the Patent, advance orders and notification of maintenance fees will be mailed to the current correspondence address as indicated unless corrected below or directed otherwise in Block 1, by (a) specifying a new correspondence address; and/or (b) indicating a separate "FEE ADDRESS" for maintenance fee notifications.

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7590

04/21/2004

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I hereby certify that this Fee(s) Transmittal is being deposited with the United States Postal Service with sufficient postage for first class mail in an envelope addressed to the Mail Stop ISSUE FEE address above, or being facsimile transmitted to the USPTO. on the date indicated below.

	ansimited to the OSI TO, on the date indicated below.
(Depositor's name)	
(Signature)	
(Date)	

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nonprovisional	NO	\$1330		\$300	\$1630	07/21/2004
EXAMINER		ART UNIT		CLASS-SUBCLASS	7	
SANTIAGO	SANTIAGO, MARICELI			313-309000	_	
1. Change of correspondence address or indication of "Fee Address" (37 CFR 1.363).			2. For printing on the patent front page, list (1) the names of up to 3 registered patent attorneys or agents OR, alternatively, (2) the name of a single firm (having as a member a registered attorney or 2			
☐ Change of correspondence address (or Change of Correspondence Address form PTO/SB/122) attached.						···
☐ "Fee Address" indication (or "Fee Address" Indication form PTO/SB/47; Rev 03-02 or more recent) attached. Use of a Customer Number is required.			d the names of up to 2 regis or agents. If no name is liste inted.			

3. ASSIGNEE NAME AND RESIDENCE DATA TO BE PRINTED ON THE PATENT (print or type)

PLEASE NOTE: Unless an assignee is identified below, no assignee data will appear on the patent. Inclusion of assignee data is only appropriate when an assignment has been previously submitted to the USPTO or is being submitted under separate cover. Completion of this form is NOT a substitute for filing an assignment.

(A) NAME OF ASSIGNEE

(B) RESIDENCE: (CITY and STATE OR COUNTRY)

Please check the appropriate assignee category or category	gories (will not be printed on the patent);	☐ individual	corporation or other private group entity	o governmen		
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☐ Issue Fee	☐ A check in the amo	☐ A check in the amount of the fee(s) is enclosed.				
☐ Publication Fee	☐ Payment by credit of	□ Payment by credit card. Form PTO-2038 is attached.				
☐ Advance Order - # of Copies	☐ The Director is hereby authorized by charge the required fee(s), or credit any overpayment, to Deposit Account Number(enclose an extra copy of this form).					
Director for Patents is requested to apply the Issue Fee	and Publication Fee (if any) or to re-apply	any previously p	aid issue fee to the application identified abo	ve.		
(Authorized Signature)	(Date)	<del> </del>		<del></del>		

NOTE; The Issue Fee and Publication Fee (if required) will not be accepted from anyone other than the applicant; a registered attorney or agent; or the assignee or other party in interest as shown by the records of the United States Patent and Trademark Office.

This collection of information is required by 37 CFR 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, Alexandria, Virginia 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, Alexandria, Virginia 22313-1450.

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# UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

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09/845,845	04/30/2001	Xia Sheng	10007799-1 3212		
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HEWLETT-PACKARD COMPANY			SANTIAGO,	SANTIAGO, MARICELI	
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P.O. Box 272400 Fort Collins, CO 80	0527 2400		ART UNIT	PAPER NUMBER	
Ton Comms, CO 80	3327-2400		2879		
			DATE MAILED: 04/21/200	4	

# Determination of Patent Term Adjustment under 35 U.S.C. 154 (b)

(application filed on or after May 29, 2000)

The Patent Term Adjustment to date is 248 day(s). If the issue fee is paid on the date that is three months after the mailing date of this notice and the patent issues on the Tuesday before the date that is 28 weeks (six and a half months) after the mailing date of this notice, the Patent Term Adjustment will be 248 day(s).

If a Continued Prosecution Application (CPA) was filed in the above-identified application, the filing date that determines Patent Term Adjustment is the filing date of the most recent CPA.

Applicant will be able to obtain more detailed information by accessing the Patent Application Information Retrieval (PAIR) system (http://pair.uspto.gov).

Any questions regarding the Patent Term Extension or Adjustment determination should be directed to the Office of Patent Legal Administration at (703) 305-1383. Questions relating to issue and publication fee payments should be directed to the Customer Service Center of the Office of Patent Publication at (703) 305-8283.

	Application No.	Applicant(s)
	09/845,845	SHENG ET AL.
Notice of Allowability	Examiner	Art Unit
	Mariceli Santiago	2879
The MAILING DATE of this communicati n appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313 1. This communication is responsive to <u>Amendment filed</u> . 2. The allowed claim(s) is/are 11,14 and 410.	ears on the cover sheet with the co (OR REMAINS) CLOSED in this applied or other appropriate communication GHTS. This application is subject to	orrespondence address blication. If not included will be mailed in due course. THIS
3. Mathematical The drawings filed on 30 April 2001 are accepted by the Ex	kaminer.	
<ul> <li>4. Acknowledgment is made of a claim for foreign priority una a) All b) Some* c) None of the: <ol> <li>Certified copies of the priority documents have</li> <li>Certified copies of the priority documents have</li> <li>Copies of the certified copies of the priority documents have</li> <li>Copies of the certified copies of the priority documents have</li> <li>International Bureau (PCT Rule 17.2(a)).</li> </ol> </li> <li>* Certified copies not received: <ol> <li>Applicant has THREE MONTHS FROM THE "MAILING DATE" on the delow. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.</li> </ol> </li> <li>5. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give</li> </ul>	been received.  been received in Application No cuments have been received in this of this communication to file a reply ENT of this application.	national stage application from the complying with the requirements
<ul> <li>6. CORRECTED DRAWINGS (as "replacement sheets") mus</li> <li>(a) including changes required by the Notice of Draftspers</li> <li>1) hereto or 2) to Paper No./Mail Date</li> <li>(b) including changes required by the attached Examiner's Paper No./Mail Date</li> <li>Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the stacked Examiner's comment regarding REQUIREMENT in the sta</li></ul>	t be submitted. on's Patent Drawing Review ( PTO- s Amendment / Comment or in the C 84(c)) should be written on the drawing he header according to 37 CFR 1.121(c) sit of BIOLOGICAL MATERIAL n	948) attached  Office action of  Ongs in the front (not the back) of  Onust be submitted. Note the
Attachment(s)  1. ☐ Notice of References Cited (PTO-892)  2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)  3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0. Paper No./Mail Date  4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	6. ☐ Interview Summary Paper No./Mail Dat 8), 7. ☑ Examiner's Amendn	è .

#### **DETAILED ACTION**

# Response to Amendment

The Amendment, filed on April 5, 2004, has been entered and acknowledged by the Examiner.

Cancellation of claims 1-3, 5-9, 12 and 13 has been entered.

Claims 4, 10, 11 and 14 are pending in the instant application.

## **EXAMINER'S AMENDMENT**

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows:

In the Abstract, pursuant to MPEP 608.01(b), please replace the abstract in its entirety with the following paragraph,

--A high emission electron emitter includes an electron injection layer, an active layer of high porosity porous silicon material in contact with the electron injection layer, a contact layer of low porosity porous silicon material in contact with the active layer and including an interface surface with a heavily doped region, and an optional top electrode in contact with the contact layer. The contact layer reduces contact resistance between the active layer and the top electrode and the heavily doped region reduces resistivity of the contact layer thereby increasing electron emission efficiency and stable electron emission from the top electrode. The electron injection layer is made from an electrically conductive material such as n+ semiconductor, n+ single crystal silicon, a metal, a silicide, or a nitride. The active layer and the

contact layer are formed in a layer of silicon material that is deposited on the electron injection layer and then electrochemically anodized in a hydrofluoric acid solution. Prior to the anodization, the interface surface can be doped to form the heavily doped region. The layer of silicon material can be porous epitaxial silicon, porous polysilicon, porous amorphous silicon, and porous silicon carbide.--

## In the claims,

This application is in condition for allowance except for the presence of claims 15-39 to an invention non-elected without traverse. Accordingly, claims 15-39 have been cancelled.

## Allowable Subject Matter

Claims 4, 10, 11 and 14 are allowed over the prior art of record.

The following is an examiner's statement of reasons for allowance:

Regarding claim 4, the references of the Prior Art of record fails to teach or suggest the combination of the limitations as set forth in claim 4, and specifically comprising the limitation of the electrically conductive silicide being selected from the group consisting of a titanium silicide and a platinum silicide, and the electrically conductive nitride comprising a titanium nitride.

Regarding claim 10, the references of the Prior Art of record fails to teach or suggest the combination of the limitations as set forth in claim 10, and specifically comprising the limitation of the porous epitaxial silicon being a material selected from the group consisting of n- porous epitaxial silicon, p- porous epitaxial silicon and intrinsic porous epitaxial silicon.

Regarding claim 11, claim 11 is allowable for the reasons given in claim 10 because of its dependency status from claim 10.

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Art Unit: 2879

Regarding claim 14, the references of the Prior Art of record fails to teach or suggest the

combination of the limitations as set forth in claim 14, and specifically comprising the limitation

of for the porous silicon carbide, the n-type heavily doped region of the contact layer includes a

dopant material selected from the group consisting of nitrogen, phosphorus and vanadium.

Any comments considered necessary by applicant must be submitted no later than the

payment of the issue fee and, to avoid processing delays, should preferably accompany the

issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons

for Allowance."

**Contact Information** 

Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Mariceli Santiago whose telephone number is (571) 272-2464. The

examiner can normally be reached on Monday-Friday from 9:30 AM to 6:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Nimesh Patel, can be reached on (571) 272-2457. The fax phone number for the

organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is (703) 308-0956.

Mariceli Santiago Patent Examiner Art Unit 2879

NIMESHKUMAR D. PATEL SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2800